General Purpose Transistors

PNP Silicon

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

Features

- NSVM Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	-40	Vdc
Collector-Base Voltage	V _{CBO}	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ic	-200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) @T _A = 25°C Derated above 25°C	P _D	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) @T _A = 25°C Derated above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

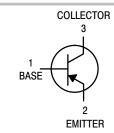
- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 × 1.0 Inch Pad



ON Semiconductor®

www.onsemi.com

GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT





CASE 463 SOT-416/SC-75 STYLE 1

MARKING DIAGRAM



2A = Device Code M = Date Code* • = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping _†
MMBT3906TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel
NSVMMBT3906TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERIS	rics	<u>.</u>			
Collector – Emitter Bre (I _C = –1.0 mAdc, I _E	V _(BR) CEO	-40	-	Vdc	
Collector – Base Break ($I_C = -10 \mu Adc, I_E$	V _(BR) CBO	-40	-	Vdc	
Emitter – Base Breakd ($I_E = -10 \mu Adc, I_C$	V _{(BR)EBO}	-5.0	-	Vdc	
Base Cutoff Current (V _{CE} = -30 Vdc, V	I _{BL}	BL –		nAdd	
Collector Cutoff Curre (V _{CE} = -30 Vdc, V		I _{CEX}	_	-50	nAdd
ON CHARACTERIST	ICS (Note 3)	•	•	•	•
DC Current Gain	[′] CE = −1.0 Vdc) CE = −1.0 Vdc) CE = −1.0 Vdc)	h _{FE}	60 80 100 60 30	- 300 - -	_
Collector – Emitter Sat ($I_C = -10 \text{ mAdc}, I_B$ ($I_C = -50 \text{ mAdc}, I_B$	= -1.0 mAdc	V _{CE(sat)}	_ _	-0.25 -0.4	Vdc
Base – Emitter Saturat ($I_C = -10 \text{ mAdc}$, I_B ($I_C = -50 \text{ mAdc}$, I_B	= -1.0 mAdc	V _{BE(sat)}	-0.65 -	-0.85 -0.95	Vdc
SMALL-SIGNAL CH	ARACTERISTICS		_		
Current – Gain – Band (I _C = –10 mAdc, V	width Product _{CE} = -20 Vdc, f = 100 MHz)	f _⊤	250	_	MHz
Output Capacitance (V _{CB} = -5.0 Vdc, I _I	₌ = 0, f = 1.0 MHz)	C_{obo}	-	4.5	pF
Input Capacitance1 (V _{EB} = -0.5 Vdc, I ₀	c = 0, f = 1.0 MHz)	C _{ibo}	_	10.0	pF
Input Impedance (V _{CE} = -10 Vdc, I _C	; = -1.0 mAdc, f = 1.0 kHz)	h _{ie}	2.0	12	kΩ
Voltage Feedback Rat (V _{CE} = -10 Vdc, I _C	tio ; = -1.0 mAdc, f = 1.0 kHz)	h _{re}	0.1	10	X 10 ⁻
Small – Signal Current (V _{CE} = –10 Vdc, I _C	h _{fe}	100	400	-	
Output Admittance (V _{CE} = -10 Vdc, I _C	h _{oe}	3.0	60	μmho	
Noise Figure (V _{CE} = -5.0 Vdc, I ₀	NF	-	4.0	dB	
SWITCHING CHARA	CTERISTICS				
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc})$	t _d	_	35	
Rise Time	$(I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	t _r	-	35	ns
Storage Time	t _s	_	225	ns	
Fall Time	$(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$	t _f	_	75	

^{3.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

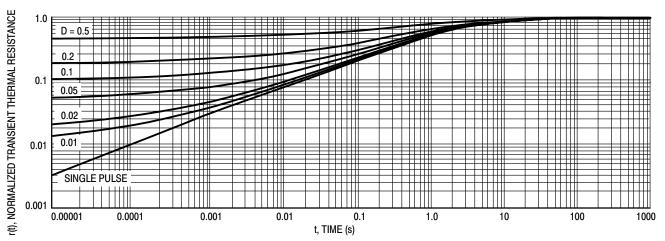
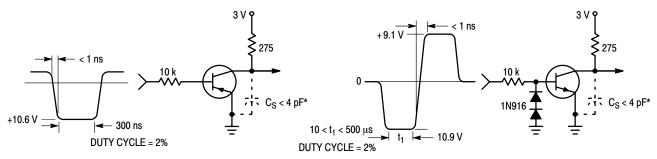


Figure 1. Normalized Thermal Response



* Total shunt capacitance of test jig and connectors

Figure 2. Delay and Rise Time Equivalent Test Circuit

Figure 3. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

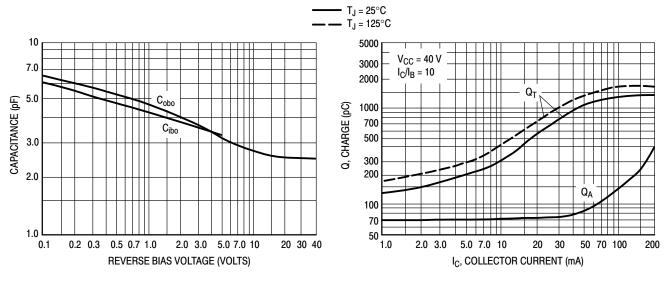


Figure 4. Capacitance

Figure 5. Charge Data

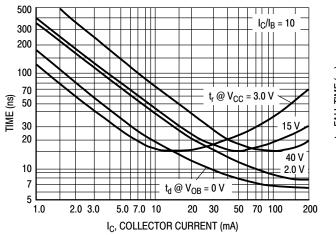


Figure 6. Turn-On Time

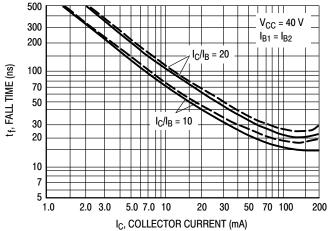
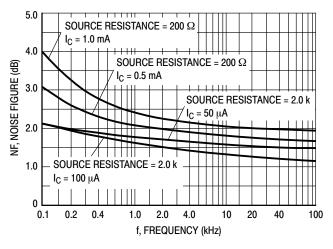


Figure 7. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



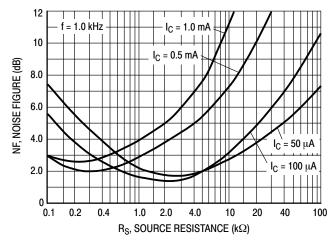
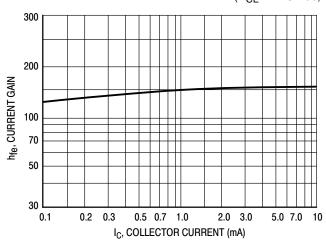


Figure 8.

Figure 9.

h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



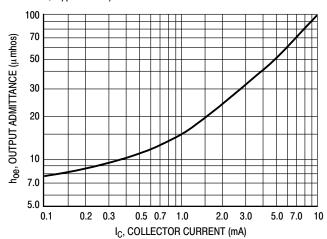
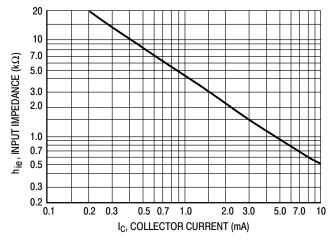


Figure 10. Current Gain

Figure 11. Output Admittance



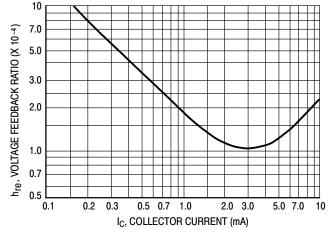


Figure 12. Input Impedance

Figure 13. Voltage Feedback Ratio

STATIC CHARACTERISTICS

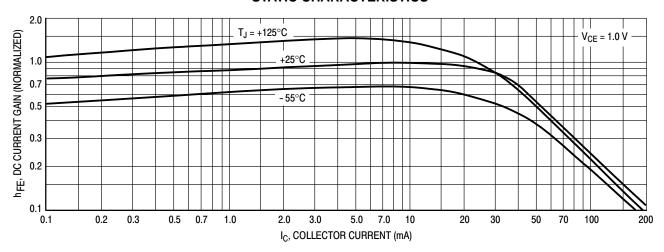


Figure 14. DC Current Gain

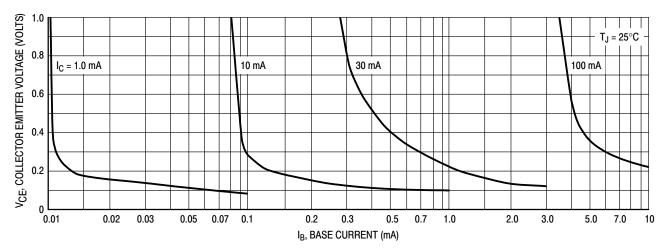


Figure 15. Collector Saturation Region

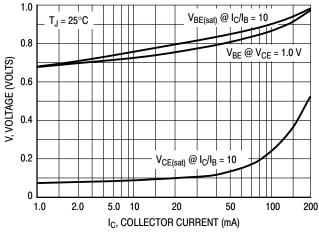


Figure 16. "ON" Voltages

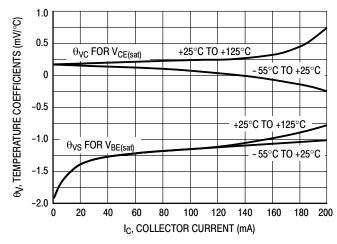
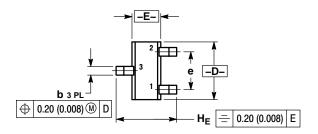


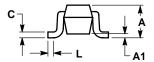
Figure 17. Temperature Coefficients

PACKAGE DIMENSIONS

SC-75/SOT-416

CASE 463 ISSUE G





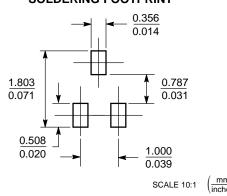
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MIL	MILLIMETERS INCHES			;	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.061	0.063	0.065
E	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC		(0.04 BSC		
L	0.10	0.15	0.20	0.004	0.006	0.008
HF	1.50	1.60	1.70	0.060	0.063	0.067

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnif

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

MMBT3906TT1G NSVMMBT3906TT1G